7.9 V Unidirectional ESD and Surge Protection **Device**

The NSPU3071 is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, high peak pulse current handling capability and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, tablets, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

Features

- Low Clamping Voltage
- Low Leakage
- Small Body Outline: 1.0 mm x 0.6 mm
- Protection for the Following IEC Standards: IEC61000-4-2 Level 4: ±30 kV Contact Discharge IEC61000-4-5 (Lightning): 25 A (8/20 μs)
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- USB V_{BUS} and CC Line Protection
- Microphone Line Protection
- GPIO Protection

Table 1. MAXIMUM RATINGS

IEC61000–4–5 (Lightning): 25 A		charge		FO
• These Devices are Pb-Free, Haloge	en Free/BFR	Free and a	re RoHS	
Compliant				0,0,0
 Typical Applications USB V_{BUS} and CC Line Protection Minucleum Line Partection 	0	CON	ME	YOUR BINFE
Microphone Line Protection	10	E X	P_{\sim}	Dev
GPIO Protection		, 4, <u>,</u>	C Y	NSPU307
Table 1. MAXIMUM RATINGS	NO	CO TI	1r	NSP0307
Rating	Symbol	Value	Unit	+For inform
IEC 61000-4-2 (ESD) Contact	err	±30	kV	including refer to ou
Air	A.S.	±30		Brochure
Operating Junction Temperature Range	ΤJ	–65 to + 150	°C	
Storage Temperature Range	T _{STG}	–65 to + 150	°C	
Minimum Peak Pulse Current	I _{PP}	25	А	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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Specific Device Code 7Ú = Date Code Pb-Free Package

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ORDERING INFORMATION

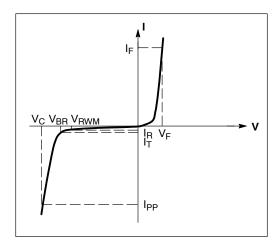
Device	Package	Shipping [†]
NSPU3071N2T5G	X2DFN2 (Pb-Free)	TBD / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Table 2. ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter			
I _{PP}	Maximum Reverse Peak Pulse Current			
V _C	Clamping Voltage @ I _{PP}			
V _{RWM}	Working Peak Reverse Voltage			
I _R	Maximum Reverse Leakage Current @ V _{RWM}			
V _{BR}	Breakdown Voltage @ I _T			
Ι _Τ	Test Current			

*See Application Note AND8308/D for detailed explanations of datasheet parameters.



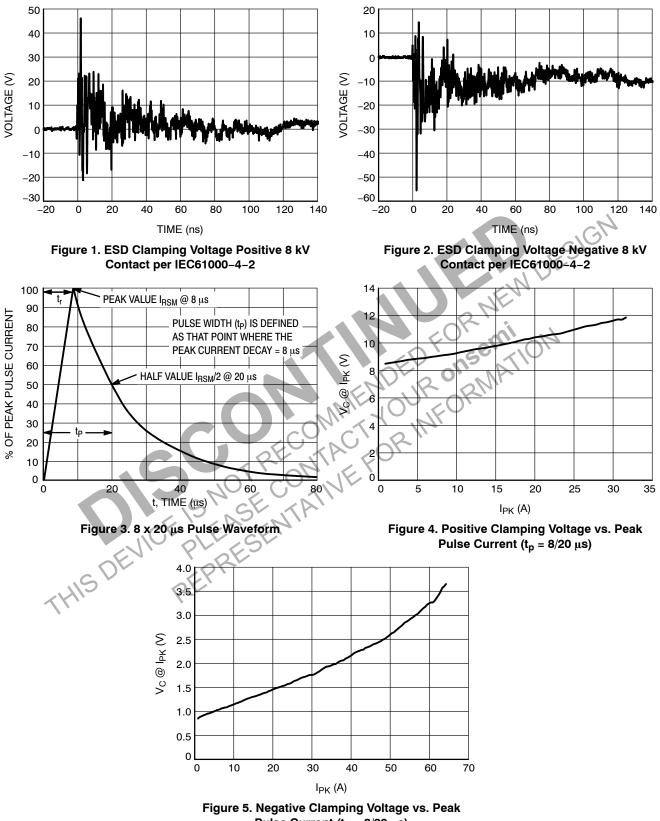
Uni-Directional Surge Protection

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	I/O Pin to GND		, Or	7.9	V
Breakdown Voltage	V _{BR}	I _T = 1 mA, I/O Pin to GND	7.95	8.4	8.8	V
Reverse Leakage Current	I _R	V _{RWM} = 7.9 V, I/O Pin to GND	Nr	0.01	1.0	μA
Clamping Voltage (Note 1)	V _C	IEC61000-4-2, ± 8 kV Contact	See	Figures 1	& 2	V
Clamping Voltage TLP (Note 2)	V _C	I _{PP} = 8 A IEC61000–4–2 Level 2 Equivalent (±4 kV Contact, ± 8 kV Air)	sent	91		V
		I _{PP} = 16 A IEC61000–4–2 Level 4 Equivalent (±8 kV Contact, ±15 kV Air)	21/12	9.5		
Reverse Peak Pulse Current	I _{PP}	IEC61000-4-5 (8x20 μs) per Figure 3	25	28.5		A
Clamping Voltage 8x20 µs Waveform per Figure 3	Vc	lpp = 10 A lpp = 25 A		9.1 10.8	9.6	V
Dynamic Resistance	R _{DYN}	100 ns TLP Pulse		0.05		Ω
Junction Capacitance	C,I	V _B = 0 V, f = 1/MHz		175	200	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
1. For test procedure see application note AND8307/D
2. ANSI/ESD STM5.5.1 – Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model. TLP conditions: Z₀ = 50 Ω, t_p = 100 ns, t_r = 1 ns, averaging window; t₁ = 70 ns to t₂ = 90 ns.

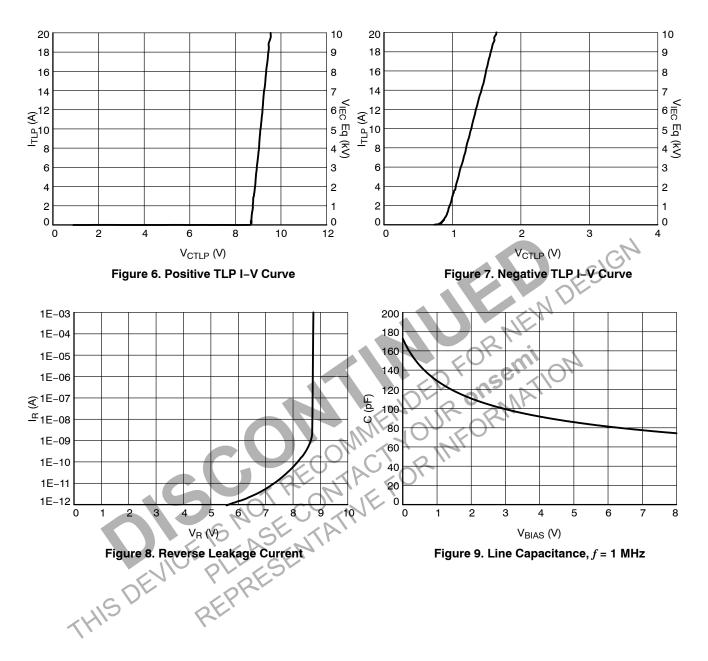
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TYPICAL CHARACTERISTICS



Pulse Current ($t_p = 8/20 \ \mu s$)

TYPICAL CHARACTERISTICS



Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I–V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 10. TLP I–V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 11 where an 8 kV IEC 61000–4–2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I–V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels. For more information on TLP measurements and how to interpret them please refer to AND9007/D.

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.

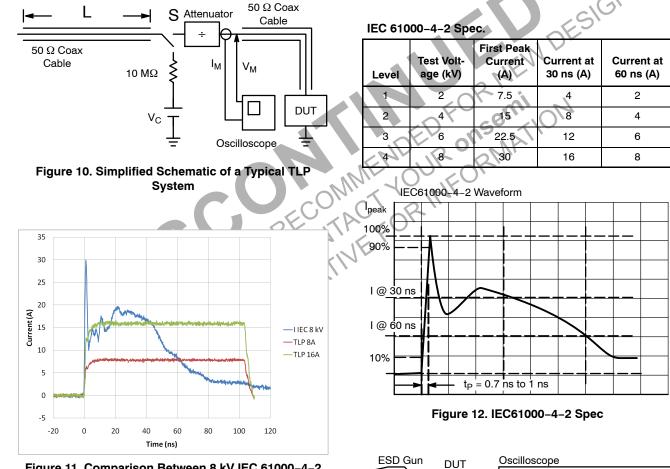


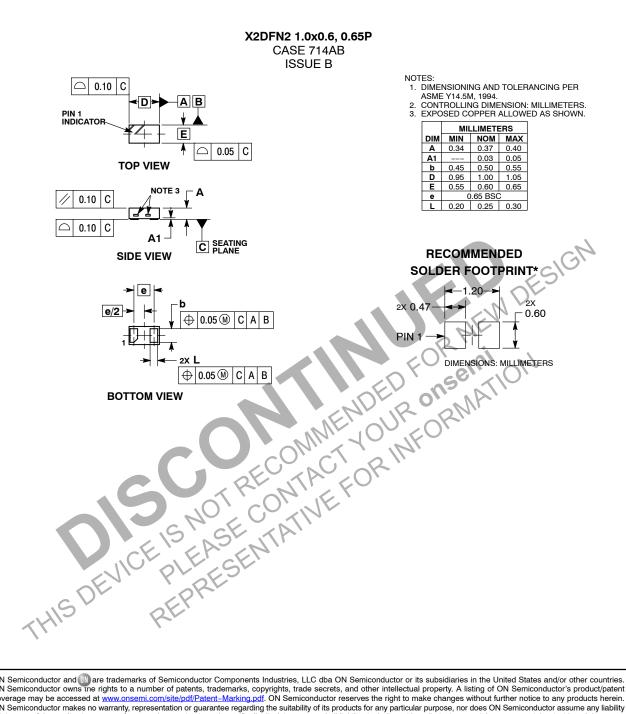
Figure 11. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms



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Figure 13. Diagram of ESD Test Setup

PACKAGE DIMENSIONS



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